

PJQ2461-AU 60V P-Channel Enhancement Mode MOSFET DFN2020B-6L -60 V -2.4 A Voltage Current **Features** • R_{DS(ON)}, V_{GS}@-10V, I_D@-2A<170mΩ • $R_{DS(ON)}$, V_{GS} @-4.5V, I_D @-1.5A<220m Ω • High switching speed • Improved dv/dt capability • Low gate charge • Low reverse transfer capacitance • AEC-Q101 qualified • Lead free in compliance with EU RoHS 2.0 • Green molding compound as per IEC 61249 standard D S **Mechanical Data** • Case : DFN2020B-6L Package 3 • Terminals : Solderable per MIL-STD-750, Method 2026 • Approx. Weight : 0.0003 ounces, 0.0086 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V _{DS}	-60		
Gate-Source Voltage		V _{GS}	<u>+</u> 20		
Continuous Drain Current (Note 4)	T _A =25°C		-2.4		
	T _A =70°C	lo l	-1.9	Α	
Pulsed Drain Current (Note 1)		I _{DM}	-9.6		
	T _A =25°C	_	2		
Power Dissipation	T _A =70°C	PD P	1.3	W	
Single Pulse Avalanche Energy (Note 6)		Eas	32	mJ	
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	٥C	
Typical Thermal Resistance - Junction to Ambient ^(Note 4,5)		Reja	62.5	°C/W	



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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS} V _{GS} =0V, I _D =-250uA	V_{GS} =0V, I_{D} =-250uA	-60	-	-	- v
Gate Threshold Voltage	$V_{\text{GS(th)}}$	V _{DS} =V _{GS} , I _D =-250uA	-1.0	-1.88	-2.5	
Drain-Source On-State Resistance	$R_{\text{DS(on)}}$	V_{GS} =-10V, I_{D} =-2A	-	140	170	mΩ
		V _{GS} =-4.5V, I _D =-1.5A	-	190	220	
Zero Gate Voltage Drain Current	IDSS	V _{DS} =-60V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	lgss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Qg	V _{DS} =-30V, I _D =-2A, V _{GS} =-10V ^(Note 1,2)	-	8.3	_	nC
Gate-Source Charge	Qgs		-	1.8	-	
Gate-Drain Charge	Q_gd		-	1.6	-	
Input Capacitance	Ciss	V _{DS} =-30V, V _{GS} =0V, f=1MHZ	-	430	-	pF ns
Output Capacitance	Coss		-	33	-	
Reverse Transfer Capacitance	Crss		-	29	-	
Turn-On Delay Time	td _(on)	V_{DD} =-30V, I _D =-1A, V _{GS} =-10V, R _G =6Ω ^(Note 1,2)	-	5.1	-	
Turn-On Rise Time	tr		-	20	-	
Turn-Off Delay Time	td _(off)		-	36	-	
Turn-Off Fall Time	tf		-	11	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	la la		-	-1.5	А	
Diode Forward Current	ls		-	_	-1.5	
Diode Forward Voltage	V_{SD}	Is=-1A, V _{GS} =0V	-	-0.78	-1	V

NOTES :

- 1. Pulse width <300us, Duty cycle <2%.
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- R_{€JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=1mH, I_{AS}=-8A, V_{DD}=-25V, V_{GS}=-10V
- 7. Guaranteed by design, not subject to production testing.

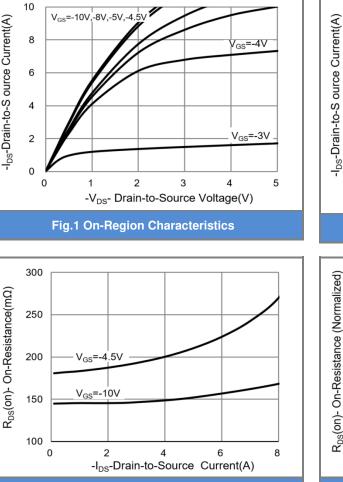
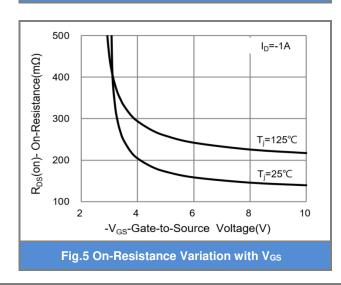
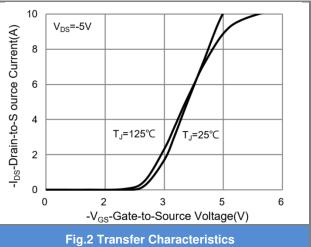


Fig.3 On-Resistance vs. Drain Current





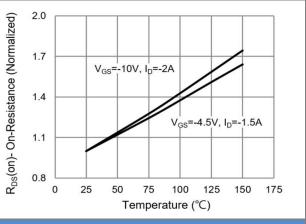
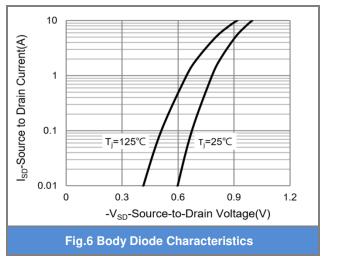


Fig.4 On-Resistance vs. Junction temperature





-I_{DS}-Drain-to-S ource Current(A)

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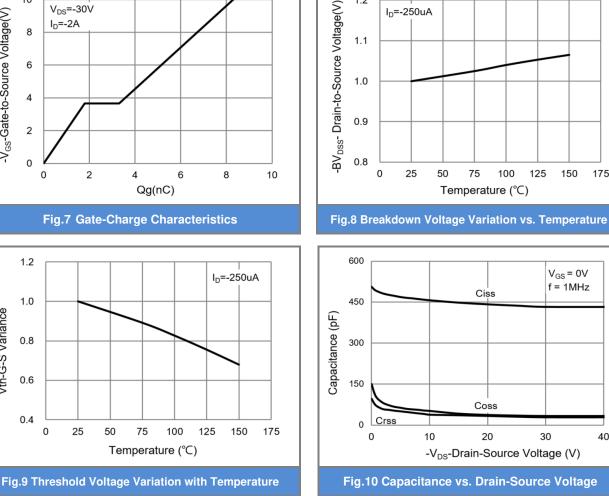
TYPICAL CHARACTERISTIC CURVES



June 17,2021

0.0001

0.001



1.2

1.1

I_D=-250uA

Normalized Transient Thermal Impedance Operation this area is 10 Drain-to-S ource Current - I_D (A) Limited by R_{DS(ON)} 10us 1 D=0.5 100us 1 0.1 1ms 0.0 0.1 10ms 0.01 DC 0.01 0.01 Notes: 1. T_J=150°C 2. T_A=25°C Single Pu 3. Single pulse VI-HL Z 0.001 0.001 0.00001 0.01 0.1 1 10 100 -V_{DS}-Drain-Source Voltage (V) Fig.11 Maximum Safe Operating Area.

Fig.12 Normalized Transient Thermal Impedance

0.01

t, Pulse Width PW (s)

T_{J,PK}=T_A+P_{DM}*Z_{TH-JA}*R_{TH-JA}

1

R_{TH-JA} = 62.5 °C/W

 $T_A = 25^{\circ}C$

0.1



10

8

6

4

2

0

1.2

1.0

0.8

0.6

0.4

0

Vth-G-S Variance

0

-V_{GS}-Gate-to-Source Voltage(V)

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V_{DS}=-30V

I_D=-2A

TYPICAL CHARACTERISTIC CURVES



175

40

150

10

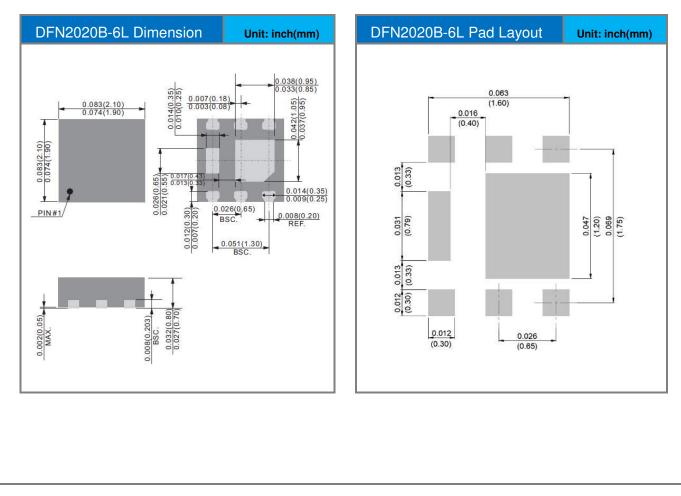


PJQ2461-AU

Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ2461-AU_R1_000A1	DFN2020B-6L	3K pcs / 7" reel	461	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout





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